

Data Sheet January 2000 File Number 3212.2

30A, 600V Ultrafast Diode

The RURG3060 is an ultrafast diode with soft recovery characteristics ($t_{rr} < 55$ ns). It has low forward voltage drop and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristic minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA09903.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURG3060	TO-247	RURG3060

NOTE: When ordering, use the entire part number.

Symbol



Features

	Ultrafast with Soft Recovery
•	Operating Temperature
•	Reverse Voltage

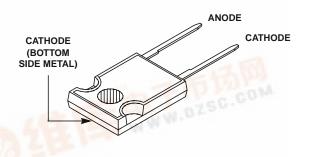
- Avalanche Energy Rated
- · Planar Construction

Applications

- · Switching Power Supplies
- Power Switching Circuits
- General Purpose

Packaging

JEDEC STYLE 2 LEAD TO-247



Absolute Maximum Ratings T_C = 25°C, Unless Otherwise Specified

	RURG3060	UNITS
Peak Repetitive Reverse VoltageV _{RRM}	600	V
Working Peak Reverse Voltage	600	V
DC Blocking VoltageV _R	600	V
Average Rectified Forward Current $I_{F(AV)}$ ($T_{C} = 130^{\circ}C$)	30	Α
Repetitive Peak Surge CurrentIFRM (Square Wave, 20kHz)	70	Α
Nonrepetitive Peak Surge Current	325	Α
Maximum Power Dissipation	125	W
Ava <mark>lanche Energy (See F</mark> igures 7 and 8)	20	mJ
Operating and Storage Temperature	-65 to 175	оС



 $\textbf{Electrical Specifications} \hspace{0.5cm} \textbf{T}_{C} = 25^{o}\text{C}, \hspace{0.1cm} \textbf{Unless Otherwise Specified}$

SYMBOL	TEST CONDITION	TYP	MAX	UNITS
V _F	I _F = 30A	-	1.5	V
	$I_F = 30A$, $T_C = 150^{\circ}C$	-	1.3	V
I _R	V _R = 600V	-	250	μΑ
	$V_R = 600V, T_C = 150^{\circ}C$	-	1	mA
t _{rr}	$I_F = 1A$, $dI_F/dt = 100A/\mu s$	-	55	ns
	$I_F = 30A$, $dI_F/dt = 100A/\mu s$	-	60	ns
t _a	$I_F = 30A$, $dI_F/dt = 100A/\mu s$	30	-	ns
t _b	$I_F = 30A$, $dI_F/dt = 100A/\mu s$	20	-	ns
$R_{ heta JC}$		-	1.2	oC/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 6), summation of t_a + t_b .

t_a = Time to reach peak reverse current (See Figure 6).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6).

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

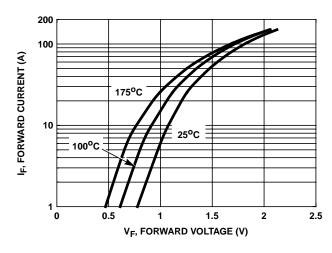


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

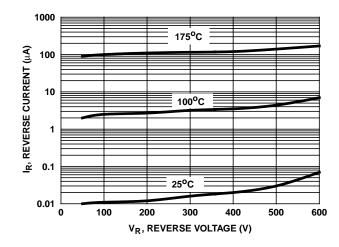


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

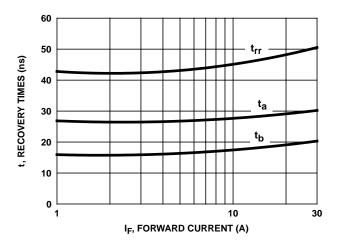


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

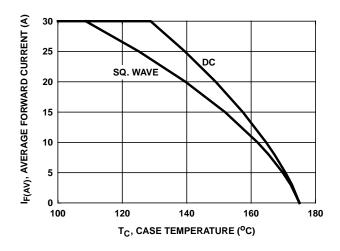


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

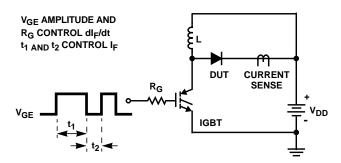


FIGURE 5. t_{rr} TEST CIRCUIT

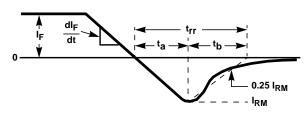


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

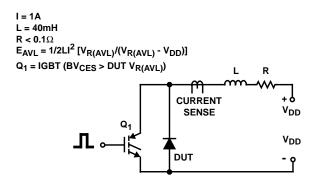


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

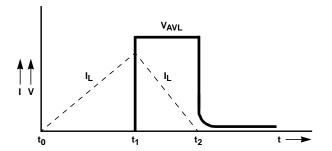


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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